1 Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 6 A/µs.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	UNIT
V _{drm}	Repetitive peak off-state voltage	600	V
I _{t(rms)}	RMS on-state current	8	A
I _{tsm}	Non-repetitive peak on-state current	65	A

SYMBOL

T2

PIN CONFIGURATION

tab

2

3

1

LIMITING VALUES

PINNING - SOT428

PIN

1

2

3

tab

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{drm}	Repetitive peak off-state voltage		-	600 ¹	V
I _{T(RMS)} I _{TSM}	RMS on-state current Non-repetitive peak on-state current	full sine wave; $T_{mb} \le 102 \degree C$ full sine wave; $T_j = 25 \degree C$ prior to surge	-	8	A
		t = 20 ms	-	65	A
124	1 ² t for final a	t = 16.7 ms	-	71	A A ² s
l²t dl _⊤ /dt	I ² t for fusing Repetitive rate of rise of on-state current after	t = 10 ms $I_{TM} = 12 \text{ A}; I_G = 0.2 \text{ A};$ $dI_G/dt = 0.2 \text{ A}/\mu \text{s}$	-	21	A-S
	triggering	T2+ G+	-	50	A/μs
		T2+ G-	-	50	A/μs
		T2- G- T2- G+	-	50	A/μs
	Peak gate current	12- 6+	-		A/μs A
I _{GM} V _{GM}	Peak gate voltage		-	2 5 5	V V
I P _{GM}	Peak gate power		-		W
$\begin{array}{c} P_{G(AV)}^{G(AV)} \\ T_{stg}^{} \\ T_{j} \end{array}$	Average gate power Storage temperature Operating junction temperature	over any 20 ms period	- -40 -	0.5 150 125	ວຸ ບິ V

GENERAL DESCRIPTION

Passivated, sensitive gate triac in a plastic envelope, suitable for surface

mounting, intended for use in general purpose bidirectional switching and phase control applications. This device

is intended to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

DESCRIPTION

MT1

MT2

gate

MT2

Triacs logic level

Product specification

T1

G

BT137S-600D

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-mb}	Thermal resistance junction to mounting base	full cycle half cycle	-	-	2.0 2.4	K/W K/W
R _{th j-a}	Thermal resistance junction to ambient	pcb (FR4) mounted; footprint as in Fig.14	-	75	-	K/W

STATIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

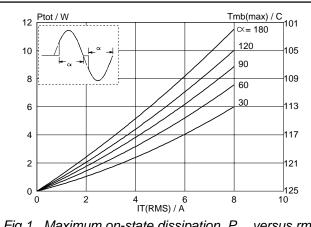
SYMBOL	PARAMETER	CONDITIONS		MIN.	TYP.	MAX.	UNIT
I _{GT}	Gate trigger current	$V_{\rm D} = 12 \text{ V}; I_{\rm T} = 0.1 \text{ A}$					
0.			T2+ G+	-	2.5	5	mA
			T2+ G-	-	3.5	5	mA
			T2- G-	-	3.5	5	mA
			T2- G+	-	6.5	10	mA
l I _L	Latching current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$					
-	-		T2+ G+	-	1.6	15	mA
			T2+ G-	-	8.5	20	mA
			T2- G-	-	1.2	15	mA
			T2- G+	-	2.5	20	mA
I _H	Holding current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$		-	1.5	10	mA
V _T	On-state voltage	$I_{T} = 10 \text{ A}$		-	1.3	1.65	V
I _H V⊤ V _{GT}	Gate trigger voltage	$\dot{V}_{\rm D} = 12 \text{ V}; \text{ I}_{\rm T} = 0.1 \text{ A}$		-	0.7	1.5	V
		$V_{\rm D} = 400 \text{ V}; I_{\rm T} = 0.1 \text{ A}; T_{\rm i} = 125^{\circ}$	C	0.25	0.4	-	V
I _D	Off-state leakage current	$V_{\rm D}^{\rm D} = V_{\rm DRM(max)}; T_{\rm j} = 125 {}^{\circ}{\rm C}$		-	0.1	0.5	mA

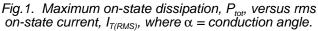
DYNAMIC CHARACTERISTICS

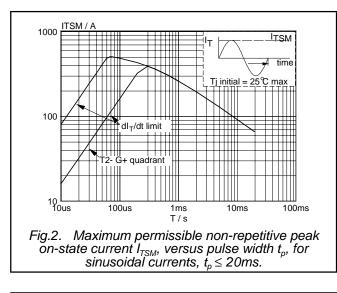
 $T_i = 25$ °C unless otherwise stated

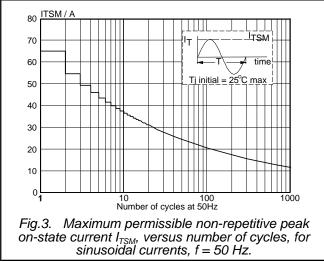
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
dV _D /dt	Critical rate of rise of	$V_{DM} = 67\% V_{DRM(max)}; T_j = 125 °C;$	-	5	-	V/µs
t _{gt}	off-state voltage Gate controlled turn-on time	exponential waveform; $R_{GK} = 1 k\Omega$ $I_{TM} = 12 A$; $V_D = V_{DRM(max)}$; $I_G = 0.1 A$; $dI_G/dt = 5 A/\mu s$	-	2	-	μs

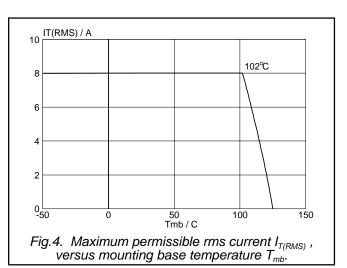
BT137S-600D











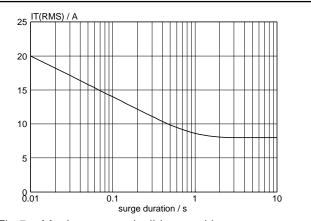
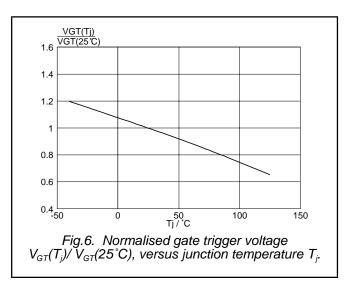
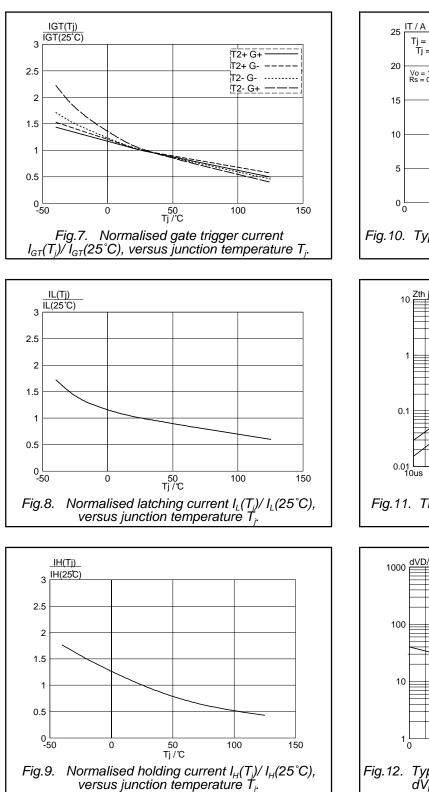
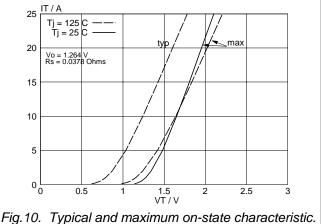


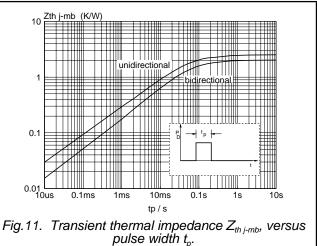
Fig.5. Maximum permissible repetitive rms on-state current $I_{T(RMS)}$, versus surge duration, for sinusoidal currents, f = 50 Hz; $T_{mb} \le 102$ °C.

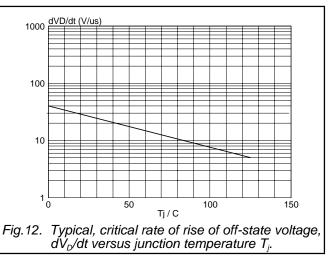


BT137S-600D



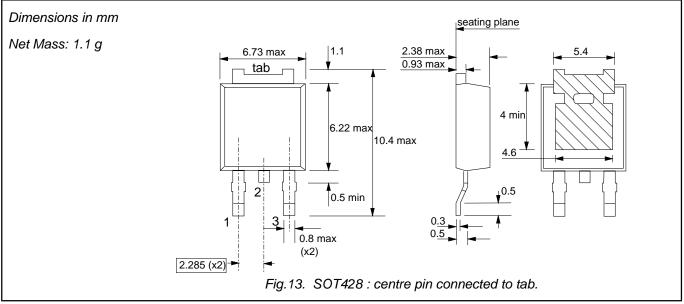




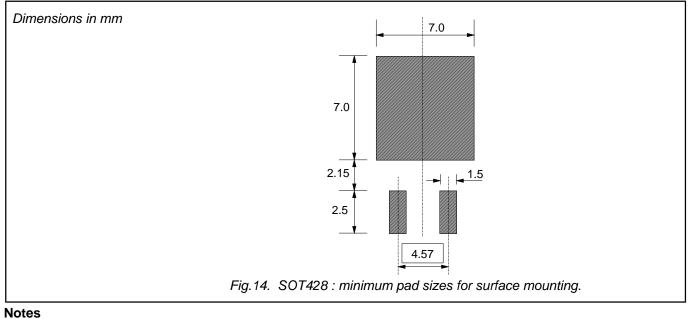


BT137S-600D

MECHANICAL DATA



MOUNTING INSTRUCTIONS



1. Plastic meets UL94 V0 at 1/8".

BT137S-600D

DEFINITIONS

DATA SHEET STATUS				
DATA SHEET STATUS ²	PRODUCT STATUS ³			
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice		
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in ordere to improve the design and supply the best possible product		
Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A		

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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² Please consult the most recently issued datasheet before initiating or completing a design.

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